

1-31-02
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jc972 U.S. PTO
10/008881
11/08/01



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)	PATENT APPLICATION
)	
Inventor: Mark Albert Crowder)	
)	
Serial No.: Not Yet Assigned)	Attorney Docket No.
)	SLA 0629
Filed: Herewith)	
)	
Title: 2N MASK DESIGN AND)	
METHOD OF SEQUENTIAL)	
LATERAL SOLIDIFICATION)	

Hon. Commissioner for Patents
Washington, D.C. 20231

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Sir:

Listed on attached Form PTO-1449 is information submitted pursuant to
37 C.F.R. §1.56. A copy of each listed publication is submitted herewith.

Applicant respectfully requests that the listed information be considered by
the Examiner and made of record in the above-identified application.

November 8, 2001
(Date)

Respectfully submitted,



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FORM PTO-1449 INFORMATION DISCLOSURE CITATION IN AN APPLICATION			DOCKET NUMBER 0629		APPLICATION NUMBER 	
			APPLICANT Mark Albert Crowder			
			FILING DATE: November 8, 2001		GROUP ART UNIT	

10/00888
 U.S. PTO
 10/00888

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FIL. DATE IF APPROP.
	6,177,301	01/23/01	Jung	438	150	05/13/99
	6,235,614	05/22/01	Yang	438	486	05/13/99
	6,274,888	08/14/01	Suzuki et al.	257	72	01/10/00

FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY/NAME	CLASS	SUB CLASS	TRANSLATION YES NO

OTHER DOCUMENTS	
	Article entitled, "Phase Transformation Mechanisms involved in Excimer Laser crystallization of Amorphous Silicon Films", by Im et al., published in Appl. Phys. Lett. 63 (14), 4 October 1993, pp 1969-1971
	Article entitled, "Sequential Lateral Solidification of Thin Silicon Films on SiO ₂ ", by Sposili et al., published in Appl. Phys. Lett. 69 (19) 4 November 1996, pp 2864-2866
	Article entitled, "Controlled Super-Lateral Growth of Si Films for Microstructural Manipulation and Optimization", by Im et al., published in Phys. Stat. Sol. (a) 166, 603 (1998), pp 603-617
	Article entitled, "Crystalline Si Films for Integrated Active-Matrix Liquid-Crystal Displays", by Im et al., published in MRS Bulletin/ March 1996, pp 39-48
	Article entitled, "Low-Temperature Single-Crystal Si TFT's Fabricated on Si Films Processed via Sequential Lateral Solidification", by Crowder et al., published in IEEE Electron Device Letters, Vol. 19, No. 8, August 1998, pp 306-308
	Article entitled, "Single-Crystal Si Films for Thin-Film Transistor Devices", by Im et al., published in Appl. Phys. Lett. 70 (25), 23 June 1997, pp 3434-3436
EXAMINER	DATE CONSIDERED